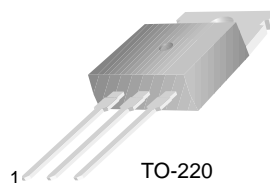


## KSE13008/13009

### High Voltage Switch Mode Application

- High Speed Switching
- Suitable for Switching Regulator and Motor Control



TO-220  
1.Base 2.Collector 3.Emitter

### NPN Silicon Transistor

#### Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CB0}$	Collector-Base Voltage	: KSE13008	600
		: KSE13009	700
$V_{CEO}$	Collector-Emitter Voltage	: KSE13008	300
		: KSE13009	400
$V_{EBO}$	Emitter-Base Voltage	9	V
$I_C$	Collector Current (DC)	12	A
$I_{CP}$	Collector Current (Pulse)	24	A
$I_B$	Base Current	6	A
$P_C$	Collector Dissipation ( $T_C=25^\circ\text{C}$ )	100	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature	- 65 ~ 150	$^\circ\text{C}$

#### Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$V_{CEO(sus)}$	Collector-Emitter Sustaining Voltage : KSE13008 : KSE13009	$I_C = 10\text{mA}, I_B = 0$	300			V
			400			V
$I_{EBO}$	Emitter Cut-off Current	$V_{EB} = 9\text{V}, I_C = 0$			1	mA
$h_{FE}$	* DC Current Gain	$V_{CE} = 5\text{V}, I_C = 5\text{A}$ $V_{CE} = 5\text{V}, I_C = 8\text{A}$	8		40	
			6		30	
$V_{CE(sat)}$	* Collector-Emitter Saturation Voltage	$I_C = 5\text{A}, I_B = 1\text{A}$ $I_C = 8\text{A}, I_B = 1.6\text{A}$ $I_C = 12\text{A}, I_B = 3\text{A}$			1	V
					1.5	V
					3	V
$V_{BE(sat)}$	* Base-Emitter Saturation Voltage	$I_C = 5\text{A}, I_B = 1\text{A}$ $I_C = 8\text{A}, I_B = 1.6\text{A}$			1.2	V
					1.6	V
$C_{ob}$	Output Capacitance	$V_{CB} = 10\text{V}, f = 0.1\text{MHz}$		180		pF
$f_T$	Current Gain Bandwidth Product	$V_{CE} = 10\text{V}, I_C = 0.5\text{A}$	4			MHz
$t_{ON}$	Turn ON Time	$V_{CC} = 125\text{V}, I_C = 8\text{A}$ $I_{B1} = - I_{B2} = 1.6\text{A}$ $R_L = 15,6\Omega$			1.1	$\mu\text{s}$
$t_{STG}$	Storage Time				3	$\mu\text{s}$
$t_F$	Fall Time				0.7	$\mu\text{s}$

\* Pulse test:  $PW \leq 300\mu\text{s}$ , Duty cycles  $\leq 2\%$

# Typical Characteristics

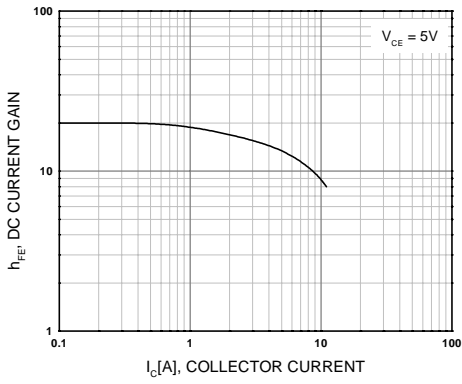


Figure 1. DC current Gain

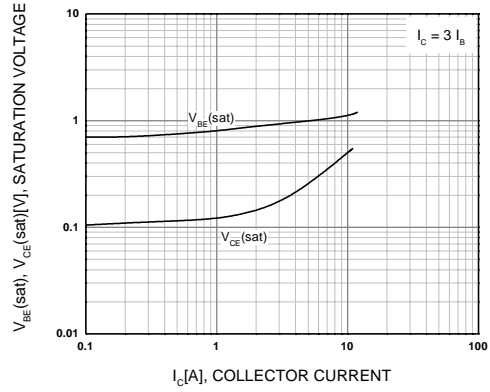


Figure 2. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

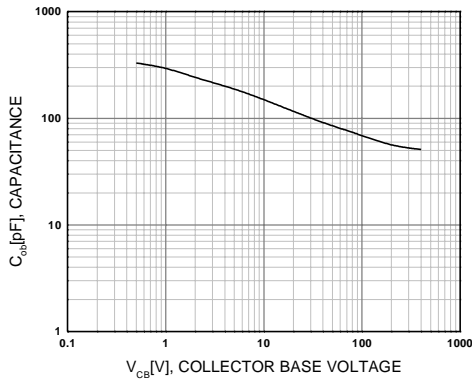


Figure 3. Collector Output Capacitance

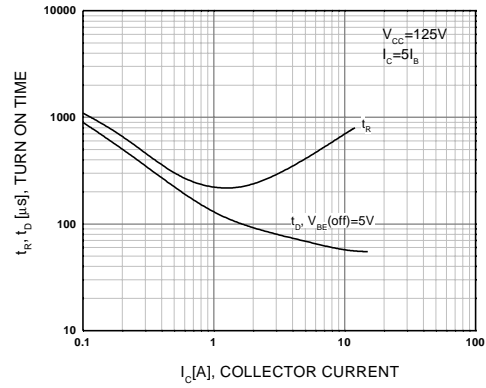


Figure 4. Turn On Time

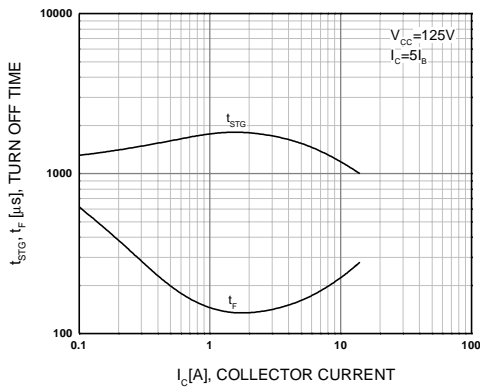


Figure 5. Turn Off Time

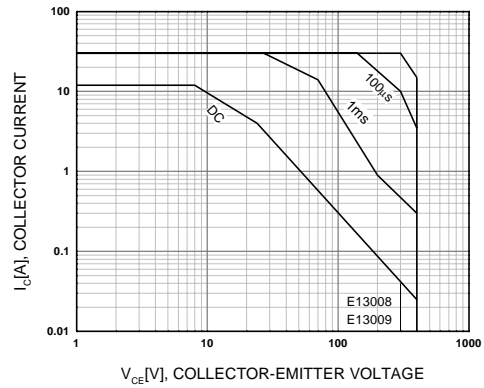


Figure 6. Safe Operating Area

# Typical Characteristics (Continued)

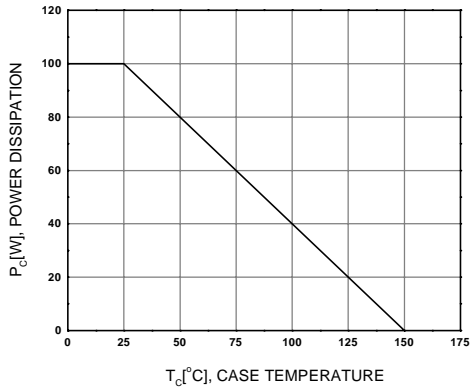


Figure 7. DC current Gain

# Package Dimensions

## TO-220

KSE13008/13009



Dimensions in Millimeters

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